

DRD3390V40

Rectifier Diode

DS6074 April 2012 (LN29429)

FEATURES

- Double Side Cooling
- High Surge Capability

APPLICATIONS

- Rectification
- Free-wheel Diode
- DC Motor Control
- Power Supplies
- Welding
- Battery Chargers

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V _{DRM} and V _{DRM} V	Conditions
DRD3390V40 DRD3390V39 DRD3390V38 DRD3390V37 DRD3390V36 DRD3390V35	4000 3900 3800 3700 3600 3500	$V_{RSM} = V_{RRM} + 100V$

Lower voltage grades available.

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DRD3390V37 for a 3700V device

KEY PARAMETERS

V_{RRM}	4000V
$I_{F(AV)}$	3388A
I _{FSM}	62500A

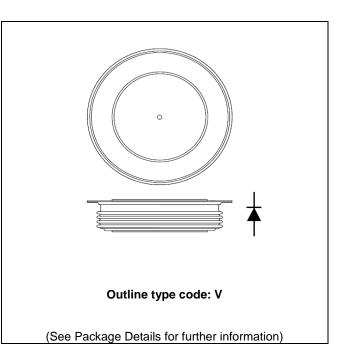


Fig. 1 Package outlines

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.



CURRENT RATINGS

T_{case} = 75°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units			
Double Si	Double Side Cooled						
$I_{F(AV)}$	Mean forward current	Half wave resistive load	4366	А			
I _{F(RMS)}	RMS value	-	6858	А			
I _F	Continuous (direct) on-state current	-	6561	А			
Single Sic	de Cooled (Anode side)						
I _{F(AV)}	Mean forward current	Half wave resistive load	2926	А			
I _{F(RMS)}	RMS value	-	4596	А			
I _F	Continuous (direct) on-state current	-	4066	А			

T_{case} = 100°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units			
Double Si	Double Side Cooled						
$I_{F(AV)}$	Mean forward current	Half wave resistive load	3388	Α			
I _{F(RMS)}	RMS value	-	5321	Α			
I _F	Continuous (direct) on-state current	-	4983	А			
Single Sig	de Cooled (Anode side)						
$I_{F(AV)}$	Mean forward current	Half wave resistive load	2232	Α			
I _{F(RMS)}	RMS value	-	3506	Α			
I _F	Continuous (direct) on-state current	-	3015	Α			



SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, T _{case} = 150°C	50.0	kA
l ² t	I ² t for fusing	$V_R = 50\% V_{RRM} - \frac{1}{4}$ sine	12.5	MA ² s
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, T _{case} = 150°C	62.5	kA
l ² t	I ² t for fusing	$V_R = 0$	19.6	MA ² s

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
$R_{\text{th(j-c)}}$	Thermal resistance – junction to case	Double side cooled	DC	-	0.0075	°C/W
		Single side cooled	Anode DC	-	0.015	°C/W
			Cathode DC	-	0.015	°C/W
R _{th(c-h)}	Thermal resistance – case to heatsink	Clamping force 43kN	Double side	-	0.002	°C/W
		(with mounting compound)	Single side	-	0.004	°C/W
T _{vj}	Virtual junction temperature	On-state (conducting)		-	160	°C
		Reverse (blocking)		-	150	°C
T _{stg}	Storage temperature range			-55	150	°C
F _m	Clamping force			38.0	47.0	kN

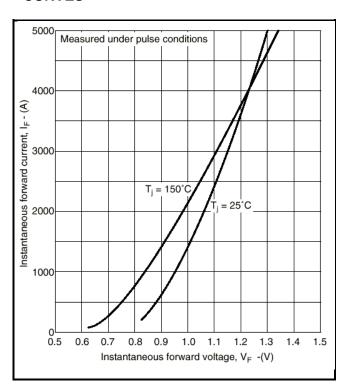
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CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
V_{FM}	Forward voltage	At 3000A peak, T _{case} = 25°C	-	1.15	V
I _{RM}	Peak reverse current	At V _{DRM} , T _{case} = 150°C	-	250	mA
Qs	Total stored charge	I _F = 2000A, dI _{RR} /dt =3A/μs	-	5000	μC
I _{rr}	Peak reverse recovery current	$T_{case} = 150$ °C, $V_R = 100$ V	-	150	Α
V _{TO}	Threshold voltage	At T _{vj} = 150°C	-	0.75	V
r _T	Slope resistance	At T _{vj} = 150°C	-	0.118	mΩ

CURVES



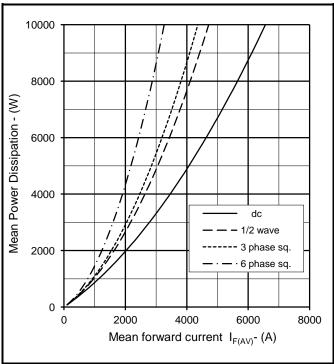


Fig.2 Maximum (limit) on-state characteristics

Fig.3 Dissipation curves

V_{TM} EQUATION

 $V_{TM} = A + Bln (I_T) + C.I_T + D.\sqrt{I_T}$

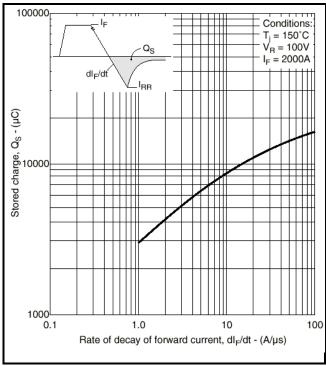
Where A = -0.15357

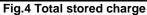
B = 0.177571

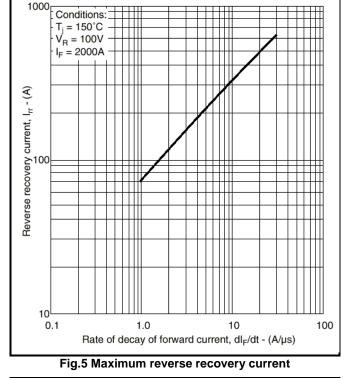
C = 0.000179

D = -0.01294

these values are valid for $T_j = 150$ °C for $I_F 500A$ to 5000A







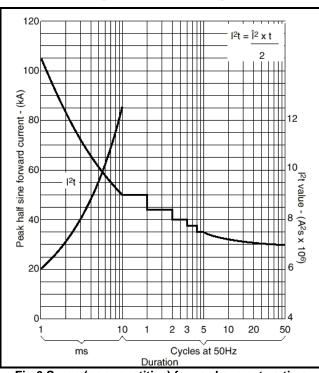


Fig.6 Surge (non-repetitive) forward current vs time (with 50% V_{RRM} at T_{case} 150°C)

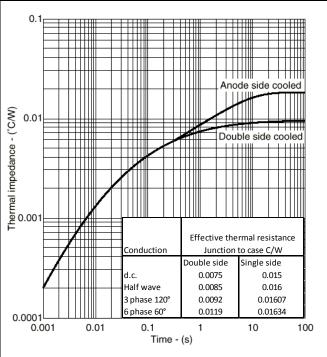
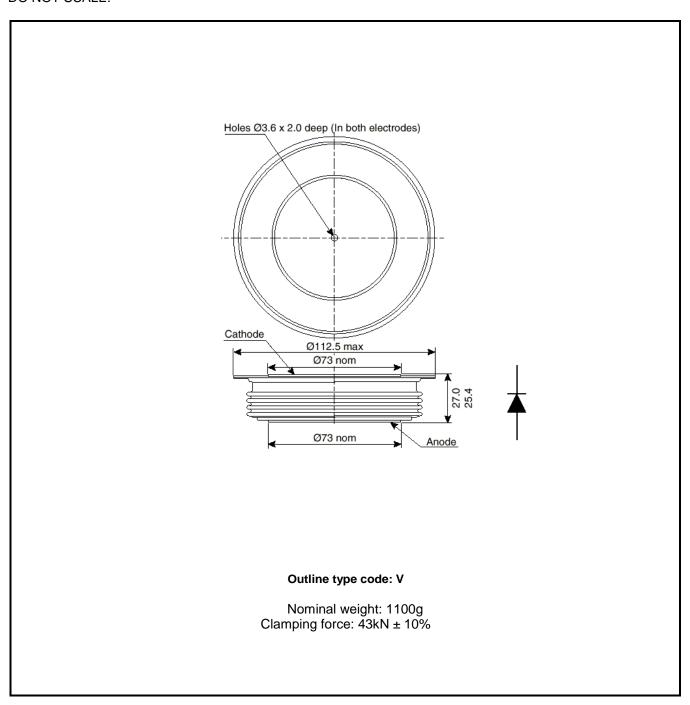


Fig.7 Maximum (limit) transient thermal impedancejunction to case



PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



Note:

Some packages may be supplied with gate and or tags.



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